

N-Channel MOSFET

General Description

The WSR55N65F is CoolFET II MOSFET family that is utilizing charge balance technology for extremely low on-resistance and low gate charge performance.

WSR55N65F is suitable for applications which require superior power density and outstanding efficiency

Features

- High ruggedness
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

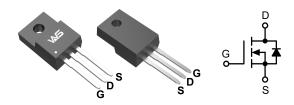
Product Summery

BV _{DSS}	R _{DS(ON)}	I _D
650V	150mΩ	55A

Applications

- Uninterruptible Power Supply(UPS)
- Power Factor Correction (PFC)

TO-220F Pin Configuration



Absolute Maximum Ratings (T_C=25°C, Unless Otherwise Noted)

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage	±30	V
I _D	Continuous Drain Current	55	Α
I _{DM}	Pulsed Drain Current ¹	130	Α
E _{AS}	Single Pulse Avalanche Energy ²	500	mJ
P_{D}	Power Dissipation (T _C =25°C)	151	W
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Тур.	Max.	Units	
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient		62	°C/W	
$R_{ heta JC}$	Thermal Resistance, Junction-to-Case		0.82	°C/W	



Electrical Characteristics (T_J=25°C, Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250μA	650			V	
$\Delta BV_{DSS}/\Delta T_{J}$	BV _{DSS} Temperature Coefficient	I _D =250μA , Reference 25°C		0.7		V/°C	
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =10V , I _D =3.2A		150	190	mΩ	
V _{GS(th)}	Gate Threshold Voltage	$V_{GS}=V_{DS}$, $I_D=250\mu A$	2.5	3.3	4.5	V	
	Drain-Source Leakage Current	V _{DS} =650V , V _{GS} =0V			1.0		
I _{DSS}		V _{DS} =520V , T _C =125°C			50	μA	
I _{GSS}	Gate-Source Leakage Current	V _{DS} =0V , V _{GS} =±30V			±100	nA	
Q_g	Total Gate Charge	14 1001/ 1/ 101/		7.27		nC	
Q_gs	Gate-Source Charge	V _{DS} =480V , V _{GS} =10V , I _D =11A		17.4			
Q _{gd}	Gate-Drain Charge	- ID-11A		43.9			
T _{d(on)}	Turn-On Delay Time			10			
T _r	Rise Time	V _{DS} =400V , I _D =13A		19.8			
T _{d(off)}	Turn-Off Delay Time	R_G =4.7 Ω , V_{GS} =13 V		45.4		ns	
T _f	Fall Time			41.4			
C _{iss}	Input Capacitance			1510			
C _{oss}	Output Capacitance	V_{DS} =100V, V_{GS} =0V, f = 1.0MHz		65		pF	
C _{rss}	Reverse Transfer Capacitance	<u></u>		2.4			

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I _S	Continuous Source Current	V =V =0V Force Current			55	Α
I _{SM}	Pulsed Source Current	V _D =V _G =0V, Force Current			165	Α
V _{SD}	Diode Forward Voltage	V _{GS} =0V , I _S =7.3A		0.812	1.5	V
t _{rr}	Reverse Recovery Time	V _{GS} =0V , I _S =11A , V _{DD} =400V		288		ns
Q _{rr}	Reverse Recovery Charge	di _F /dt=100A/μs		3.66		μC

Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2. The E_{AS} data shows Max. rating . L=0.5mH, $\,I_{AS}\!=\!7A,\,\,V_{DD}\!=\!50V,\,\,R_{G}\!=\!25\Omega$
- 3. The test condition is Pulse Test: $I_{SD} \le I_{D}$, $di/dt = 100 A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting at T_{J} =25°C
- 4. The power dissipation is limited by 150 $^{\circ}\text{C}$ junction temperature
- 5. The data is theoretically the same as $\ensuremath{I_D}$ and $\ensuremath{I_{DM}}$, in real applications , should be limited by total power dissipation.



Typical Characteristics

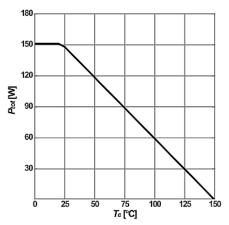


Figure1: Power dissipation (Non FullPAK)

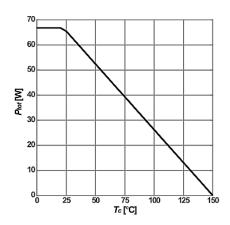


Figure3: Power dissipation $P_{\text{tot}} = f(T_{\text{C}})$

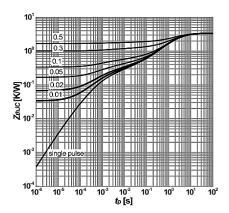


Figure 5: Max. transient thermal impedance $Z_{thJC} = f(t_p)$; parameter: D= t_p/T

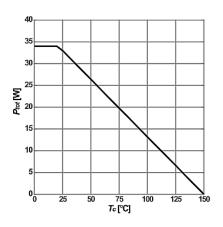


Figure2: Power dissipation (FullPAK)

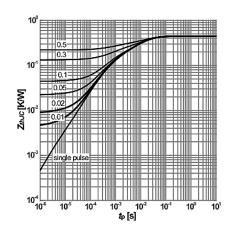


Figure4:Max. transient thermal impedance $Z_{thJC}=f(t_p)$; parameter: D= t_p/T

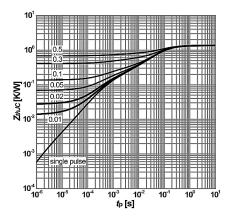


Figure6: Max. transient thermal impedance $Z_{th,JC}=f(t_p)$; parameter: D= t_p/T



Typical Characteristics (Cont.)

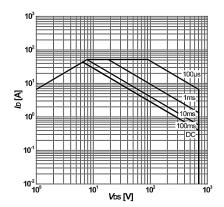


Figure 7: Safe operating area (Non FullPAK) $I_D=f(V_{DS})$; $T_J=25$ °C; D=0; parameter: t_P

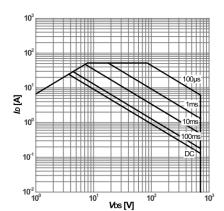


Figure9: TSafe operating area (FullPAK-TO220A) $R_{DS}(on)=f(I_D); T_J=25$ °C; parameter: V_{GS}

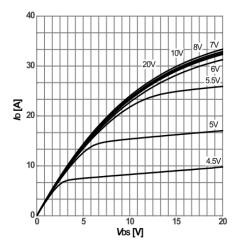


Figure 11: Typ. output characteristics

I_D=f(V_{DS}); Tj=125°C; parameter: V_{GS}

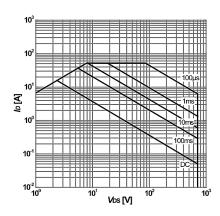


Figure8 : Safe operating area (Non FullPAK)

 $I_D=f(V_{DS})$; $T_j=25$ °C; D=0; parameter: t_p

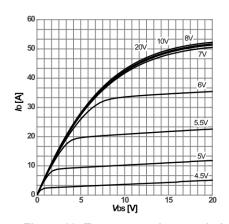


Figure 10: Typ. output characteristics $R_{DS}(on)=f(T_j); I_D=3.2A; V_{GS}=10V$

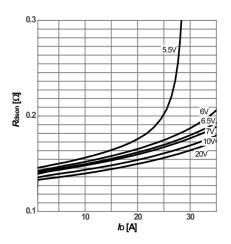
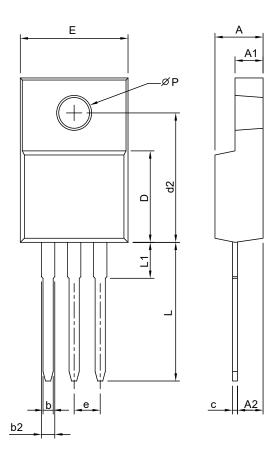


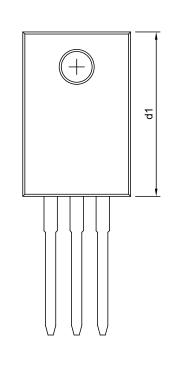
Figure 12: Type. gate charge

 $R_{DS}(on)=f(I_D); T_j=25^{\circ}C; parameter: V_{GS}$



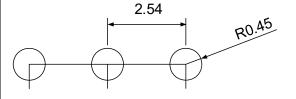
Packaging information





	TO-220F				
SYMBOL	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
А	4.20	4.80	0.165	0.189	
A1	2.34	3.20	0.092	0.126	
A2	2.10	2.90	0.083	0.114	
b	0.50	0.90	0.020	0.035	
b2	0.91	1.90	0.035	0.075	
С	0.30	0.80	0.012	0.031	
D	8.10	9.40	0.319	0.370	
d1	14.50	16.50	0.571	0.650	
d2	12.10	12.90	0.476	0.508	
E	9.70	10.70	0.382	0.421	
е	2.54 BSC		0.100	BSC	
L	13.00	14.50	0.512	0.570	
L1	1.60	4.00	0.063	0.157	
Р	3.00	3.60	0.118	0.142	

RECOMMENDED LAND PATTERN



UNIT: mm



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